

Silicon Switching Diode

Rev. V5

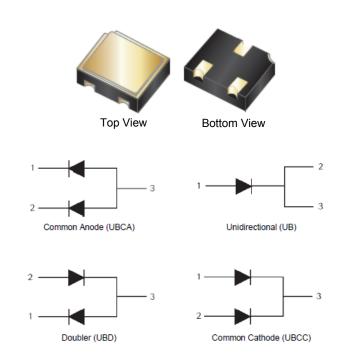
Features

- JAN, JANTX, JANTXV and JANS Qualification is available per MIL-PRF-19500/578/609 (see part nomenclature for all available options)
- Surface Mount Equivalent of JEDEC registered 1N6638 - 1N6643
- Very Low Capacitance
- Very Fast Switching Speeds with Minimal Reverse Recovery Times
- Unidirectional as well as Doubler, Common Anode and Common Cathode Polarities are Available
- RoHS Compliant by Design



The 1N66xxUB Series of switching/signal diodes feature ceramic bodied construction for military grade products per MIL-PRF-19500/578/609. These small, low capacitance diodes, with very fast switching speeds, are featured in a surface mount UB package with various polarities available.

These devices are ideally suited for high frequency data lines, RS-232 & RS-422 interface networks, and Ethernet 10 Base T, LAN & computers.



Electrical Specifications

Part #	V _{BR} @ I _R		V _{RWM}	V _{FR} / t _{FR}		C _T 1	C _T 2	trr
(add UB, UBCA, UBCC, UBD as per part nomenclature)				@ I _F = 200 mA		V _R = 0.0 V	V _R = 1.5 V	I _R = 10 mA, I _F = 10 mA
	V(pk)	μΑ	V(pk)	V(pk)	ns	pF	pF	ns
1N6638	150	100	125	5	20	2.5	2.0	4.5
1N6639	100	10	75	5	10	2.5	_	4
1N6640	75	10	50	5	10	2.5	_	4
1N6641	75	10	50	5	10	3.0	_	5
1N6642	100	100	75	5	20	5.0	2.8	5
1N6643	75	100	50	5	20	5.0	2.8	6



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Electrical Specifications

Part #		I _R			V _F @ I _F				I _F
(add UB, UBCA, UBCC, UBD as	V _R = 20 V	V _R = V _{RWM}	V _R = 20 V T _A = +150° C	$V_R = V_{RWM},$ $T_A = +150^{\circ}$ C			T _A = +150°C	T _A = -55°C	
per part nomen- clature)		_		_	٧	V	V	٧	mA
	nA	nA	μΑ	μA	Min.	Max.	Max.	Max.	(pulsed)
1N6638	35	500	50	100	_	1.1 0.8	- 0.65	1.2 —	200 10
1N6639	_	100	_	90	_	1.2		1.3	500
1N6640	_	100	_	90	0.54 0.76 0.82 0.87	0.62 0.86 0.92 1.0	_	 _ _ 1.1	1 50 100 200
1N6641	_	100	_	90	0.87	1.1	_	1.2	200
1N6642	25	500	50	100	_	0.8 1.2	0.8	 1.2	10 100
1N6643	50	500	75	100	_	0.8 1.2	0.8	 1.4	10 100

Absolute Maximum Ratings @ +25°C (unless otherwise specified)

Part # (add UB, UBCA, UBCC, UBD as per part nomenclature)		Working Peak Reverse Voltage	Average Rectified Current @ T _A = +75°C ¹	Non-Repetitive Sinusoidal Surge Current (tp = 8.3 ms)	Junction & Storage Temperature Range
1N6638	150	125			
1N6639	100	75			
1N6640	75	50			
1N6641	75	50	300 mA	2.5 A (pk)	-65°C to +200°C
1N6642	100	75			1
1N6643	75	50			

^{1.} See derating curve.



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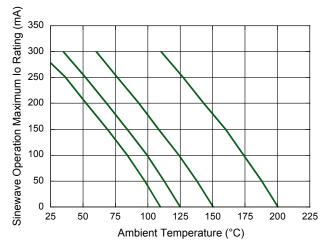
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Thermal Characteristics²

Characteristics	Symbol	Max. Value
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	325°C/W
Thermal Resistance, Junction to Solder Pad	R _{0JSP}	100°C/W

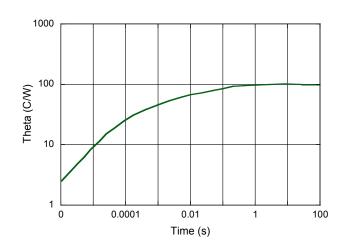
^{2.} See thermal impedance curve.

Temperature - Current Derating



Sinewave Operation 50% Duty Cycle, $R_{\rm BJA}$ (PCB) = 325°C/W. Maximum Finish-Alloy Temperature = 175°C

Thermal Impedance

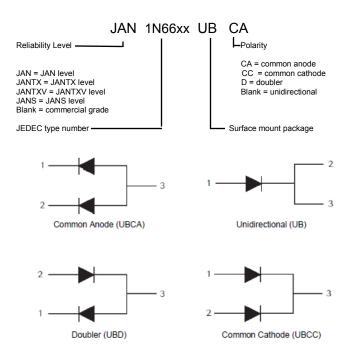




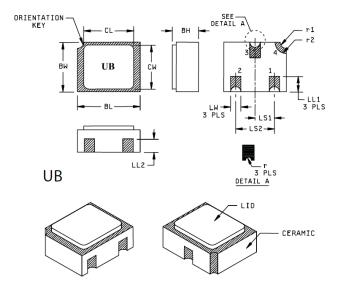
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Parts Nomenclature



Outline Drawing (UB)



Case: Ceramic

Thermals: Gold plating over nickel under plate.

Tape & Reel option: Standard per EIA-4180. Consult factory for quantities.

. Weight: <0.04 grams

Dimensions^{3,4,5,6}

Symbol	Inc	hes	Millimeters		
	Min.	Max.	Min.	Max.	
BH	0.046	0.056	1.17	1.42	
BL	0.115	0.128	2.92	3.25	
BW	0.085	0.108	2.16	2.74	
CL	-	0.128	-	3.25	
CW	-	0.108	-	2.74	
LL1	0.022	0.038	0.56	0.96	
LL2	0.017	0.035	0.43	0.89	
LS ₁	0.035	0.039	0.89	0.99	
LS ₂	0.071	0.079	1.81	2.01	
LW	0.016	0.024	0.41	0.61	
r	-	0.008	-	0.203	
r ₁	-	0.012	-	0.305	
r ₂	-	0.022	-	0.559	

- 3. Dimensions are in inches. Millimeters are given for general information only.
- 4. Hatched areas on package denote metallized areas.
- Pad 1 = Base, Pad 2 = Emitter, Pad 3 = Collector, Pad 4 = Shielding connected to the lid.
- In accordance with ASME Y14.5M, diameters are equivalent to \$\psi x\$ symbology.



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